

Gigabit Ethernet 1.25Gbps Transceiver TV8xxxx



- Maximum 80km Transmission
- 1310nm or 1550nm Transceiver for MM/SM fiber
- 1.25Gbps Gigabit Ethernet (1000Base-LX)
- Single +3.3V or +5V Power Supply
- 1X9 Duplex SC Connector

Family Model - x:3.3V or 5V

TV83xLX TV83x10 TV83x20 TV83x30 TV85x40 TV85x60 TV85x80

Features

- Compliant with IEEE 802.3z 1000BASE-LX specifications for Gigabit Ethernet
- Industry standard 1X9 package with duplex SC connector
- 1.3 μ m or 1.55 μ m uncooled InGaAsP SMQW Fabry-Perot(FP) LD or distributed feed-back(DFB) LD and APC for constant output power
- High sensitive InGaAs PIN photodiode used at wavelengths from 1.1 μ m to 1.6 μ m
- Single +3.3V or +5V power supply
- Plastic or metallized housing
- Operating temperature ; 0 to +70 $^{\circ}$ C/-40 to +85 $^{\circ}$ C
- Tested by Teradion's Reliability and Qualification Program
- Distance options
 - 550m with 50/125 μ m or 62.5/125 μ m MMF
 - 5km/10km/20km with 9/125 μ m SMF

Description

The TV8xxxx series transceivers are designed to meet the Gigabit Ethernet LX specifications. The transceivers are manufactured in 1x9 pin package with duplex SC connector interface and made of plastic or metallized housing to obtain excellent EMI shielding..

The transmitter consists of a 1.31 μ m/1.55 μ m InGaAsP SMQW laser diode(FP-LD or DFB-LD) in an optical subassembly(OSA).

The OSA is driven by a custom IC which converts differential PECL logic signals into a laser diode drive current. The receiver includes a planar InGaAs PIN photodiode mounted with a transimpedance preamplifier IC in an OSA. The OSA is mated to a custom limiting-amplifier

which provides post-amplification and signal detect function(active high).

The transceivers are designed to used in a single power supply(+3.3V or +5V) and an operating temperature range of 0°C to +70°C or -40°C to +85°C.

Applications

The transceiver operates at 1.25Gbps for Gigabit Ethernet on multimode or single mode fiber.

- Gigabit Ethernet / LAN switch
- Metro Ethernet
- High speed digital transmission
- Storage area network

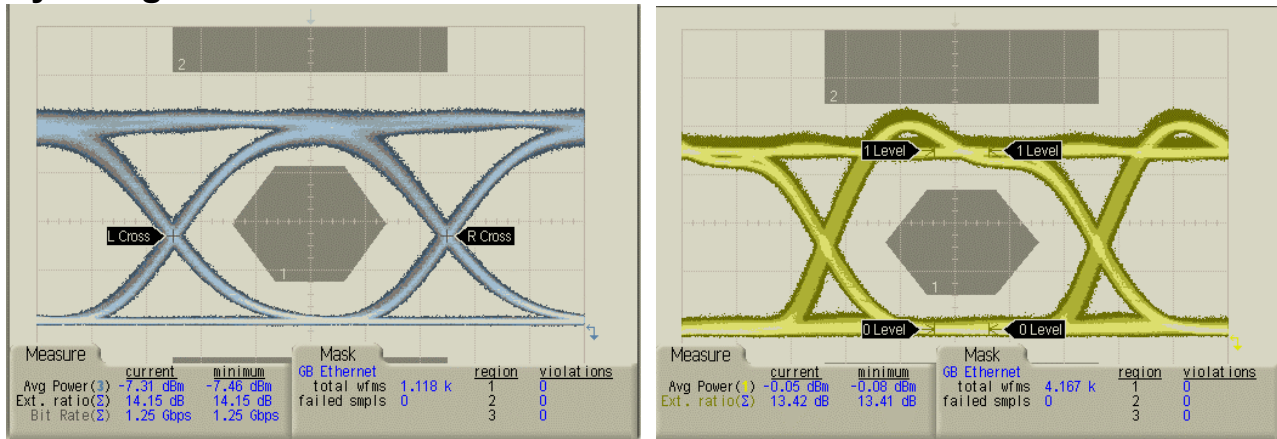
Absolute Maximum Ratings

Parameters	Symbol	Unit	Min.	Max.	Remarks
Ambient Operating Temperature	T_{op}	°C	0	70	Indoor use
			-40	85	Outdoor use
Storage Temperature	T_{stg}	°C	-40	85	
Supply Voltage	$V_{CC}-V_{EE}$	V	-0.5	6.0	
Lead Soldering Temperature/Time		°C/sec		260/10	
Relative Humidity	RH	%	-	95	

Electrical Characteristics

Parameters		Symbol	Unit	Min.	Typ.	Max.	Remarks
DC Power Supply Voltage		$V_{CC}-V_{EE}$	V	3.1 4.75	3.3 5	3.5 5.25	3.3V 5V
DC Power Supply Current		$I_{CC,TX}$ $I_{CC,RX}$	mA mA	78 90		120 115	5V option
Input Data Voltage	Low	$V_{IL}-V_{CC}$	V	-1.810 -1.165		-1.475 -0.880	3.3V/5V
	High	$V_{IH}-V_{CC}$					
Output Data Voltage	Low	$V_{OL}-V_{CC}$	V	-1.892 -1.051		-1.548 -0.879	3.3V/5V
	High	$V_{OH}-V_{CC}$					
Output SD Voltage	TTL option	Low	$V_{SD, Low}$	-		0.8	3.3V
		High	$V_{SD, High}$	2.2		-	
		Low	$V_{SD, Low}$	-		0.8	5V
		High	$V_{SD, High}$	4.2		-	

Eye Diagram



a. < 15km with 1.25Gbps filter

b. TV85580, PRBS 2²³ - 1 with 2.5Gbps filter

Fig. 1 Back-to-back

Optical Characteristics

(T_{op} = 25°C)

Parameters	Symbol	Condition	Unit	Min.	Typ.	Max.	Remark
Data Bit Rate		NRZ	Gbps		1.25		
Fiber Length 50 or 62.5µm core MMF 9µm core SMF		10 ⁻¹² BER, 1.25Gbps	km	0.55 5		80	*20km-option @1.3µm @1.3/1.5µm
TRANSMITTER							
Average Power Output	P _{OUT}	I _f =I _{BIAS} + I _{mod} /2	dBm	-9.5 -7.0 -4.0 -2.0 -1.0	-7.0 -5.5 -3.0 -1.0 0	-3.0 -3.0 -1.0 1.0 2.0	≤10km - FP 20km - FP 30/40km-DFB 60km - DFB 80km - DFB
Extinction Ratio	ER		dB	9			
Center Wavelength	λ _c	CW, @ P _{OUT}	nm	1285 1300 1280 1480	1310 1310 1310 1550	1355 1320 1335 1580	≤10km - FP 20km - FP 30km - DFB ≥40km - DFB
Spectral Width	Δλ	RMS Width Max. -20dB WD	nm			2.8 2.0	≤10km 20km
Side Mode Suppression Ratio	SMSR		dB	30			DFB-LD
Optical Rise/Fall Time	t _r /t _f	20 - 80%	nsec			0.26	
Relative Intensity Noise	RIN		dB /Hz			-120	
Total Transmitter Jitter Added at TP2			psec			227	

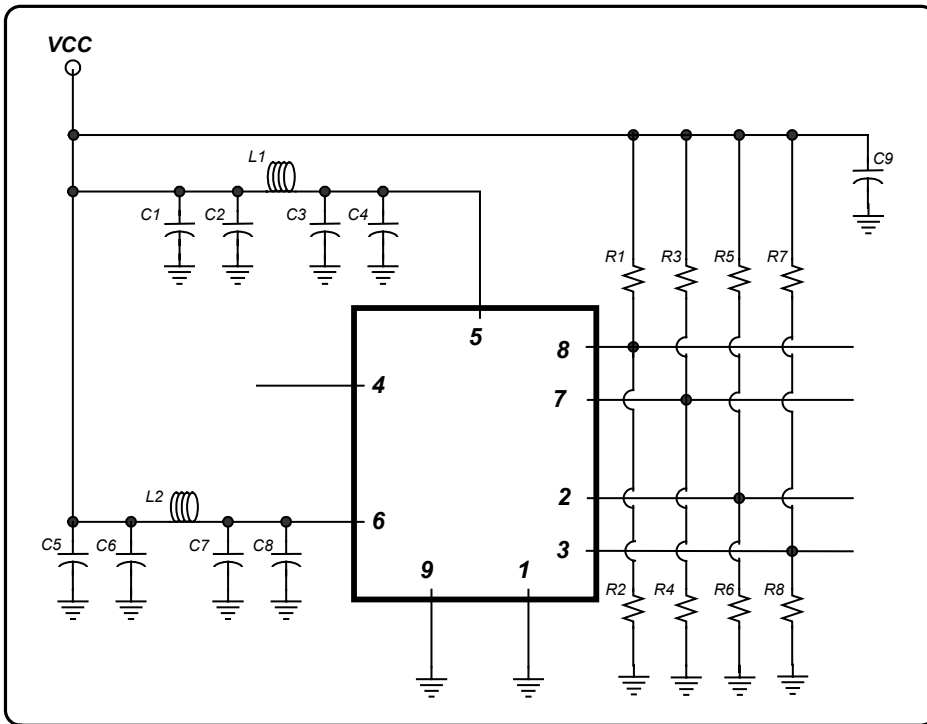
RECEIVER							
Sensitivity (Average Input Power)	$P_{IN,MIN}$	PRBS 2^7-1 , 10^{-12} BER	dBm		-22 -23 -22 -24 -26	-20 -21 -21 -22 -25	≤10km 20km 30/40km 60km 80km
Receiver Overload	$P_{IN,MAX}$		dBm	-3.0			
Electrical 3dB Upper Cutoff Frequency			MHz			1500	
Signal Detect Threshold Decreasing light input Increasing light input	P_D P_A		dBm dBm	-30		-20	
Signal Detect Hysteresis	$P_A - P_D$		dB	0.5	1.0		

Pin Descriptions

Pin No.	Symbol	Description	Level/Logic
1	V_{EER}	Rx Ground	Power supply
2	RD+	Rx Data out(+)	PECL
3	RD-	Rx Data out(-)	PECL
4	SD	RX Signal detect. (Logic HIGH for normal operation)	TTL output
5	V_{CCR}	Rx Power supply	Power supply
6	V_{CCT}	Tx Power supply	Power supply
7	TD-	Tx Data in(-)	PECL
8	TD+	Tx Data in(+)	PECL
9	V_{EET}	Tx Ground	Power supply

Recommended Interface Circuit

The transceiver can operate with PECL logic level. The interface circuit with direct-coupled PECL interface is shown in Figure 1. When interfacing with non-PECL logic level, AC coupling can be used as shown in Figure 2. The Signal Detect circuit monitors the incoming optical signal and generates a logic LOW signal when the optical signal is lower than a predefined level. The power supply filters are required for good EMI performance and should be as close to the transceiver as possible.

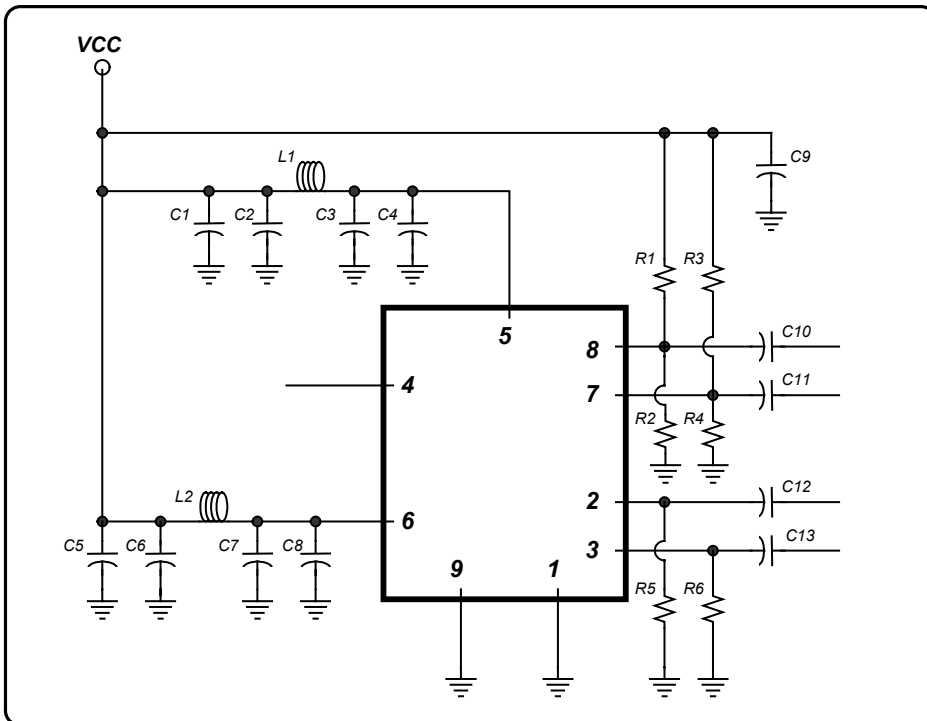


$C1=C4=C5=C8=10\mu\text{F}$,
 $C2=C3=C6=C7=0.1\mu\text{F}$,
 $C9=0.1\mu\text{F}$,

$L1=L2=1.0\mu\text{H}$ or
 Ferrite inductor

$R1=R3=R5=R7=82\Omega$
 (5.0V) or 82Ω (3.3V),
 $R2=R4=R6=R8=130\Omega$
 (5.0V) or 130Ω (3.3V),

Fig. 2 DC-Coupled PECL Interface



$C1=C4=C5=C8=10\mu\text{F}$,
 $C2=C3=C6=C7=0.1\mu\text{F}$,
 $C9=0.1\mu\text{F}$, $R1=R3=68\Omega$
 (5.0V) or 82Ω (3.3V),

$R2=R4=180\Omega$ (5.0V)
 130Ω (3.3V),
 $R5=R6=270\Omega$ (5.0V)
 or 142Ω (3.3V),

$C10=C11=C12=C13=0$
 $.1\mu\text{F}$,

$L1=L2=1.0\mu\text{H}$
 or Ferrite inductor

Figure 3. AC-Coupled PECL Interface.

Outline Diagram

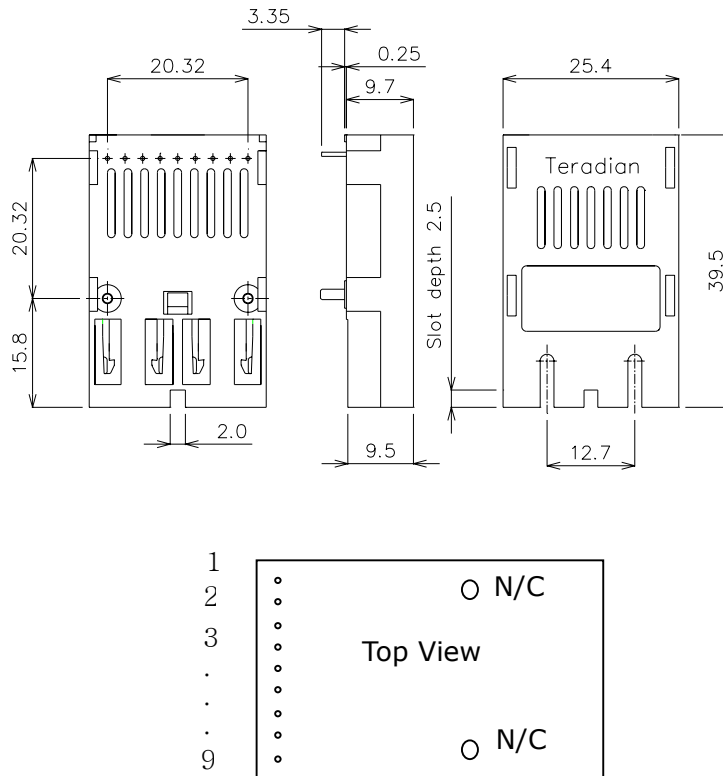


Fig.4 SC duplex Transceiver Package Dimensions [unit: mm]

! Handling Caution

The transceiver can be damaged by overvoltage and current surges. Precautions should be taken for transient power supply.

This device is susceptible to damage as a result of electrostatic discharge(ESD). Take proper precautions during both handling and testing

! Caution

- All adjustments are made at the factory before shipment to our customers. No maintenance and alteration to device is required.
- Tampering with or modifying the performance of the modules will result in voided product warranty. It may also result in improper operation of the circuitry, and possible overstress of the semiconductor components. Device degradation or product failure may result.
- Use of controls or adjustments or procedures other than those specified herein (ex : Connection of the modules to a non-approved optical source, operating above the recommended absolute maximum conditions, operating in a manner inconsistent with unit design and function) may result in hazardous radiation exposure and may be considered an act of modifying or manufacturing a laser product. The person(s) performing such an act is required by law to recertify the laser product under the provisions of US 21CFR (Subchapter J).
- The use of optical instruments with this product will increase eye hazard.

Notice

On operation, If optical connectors are unterminated, modules can emit invisible laser radiation. Avoided eye exposure to direct or indirect radiation

Ordering Information

Com pany	Func- tion	Data Rate	Wavelength	Supply Voltage	Distance	Pin	Temp. Range	Shielding
T	V	8	3	3	20	9	I	N
Tera dian	V ;TRV S ;SFF F ;SFP B ;Bi-Di TRV. (Recep- tacle) D ;Bi-Di TRV. (Pig- tailed)	1 ;155Mbps 4 ;622Mbps F ;1.06Gbps 8 ;1.25Gbps S ;2.12Gbps G ;2.5Gbps A ;Asy. Bi-Di 622M/155M E ;Asy. Bi-Di 1.25G/155M O ;Order- made	3 ;1.3μm 5 ;1.55μm 6 ;Bi-Di T1.3/R1.5 7 ;Bi-Di T1.5/R1.3 8 ;850nm A ;1470nm B ;1490nm C ;1510nm D ;1530nm E ;1550nm F ;1570nm G ;1590nm H ;1610nm M ;1270nm N ;1290nm O ;1310nm P ;1330nm Q ;1350nm R ;1370nm S ;1390nm T ;1410nm U ;1430nm W ;1450nm	3 ;3.3V 5 ;5V	SX ;Note1 02 ;2km LX ;5km 10 ;10km 15 ;15km 20 ;20km 30 ;30km 40 ;40km 60 ;60km 80 ;80km A0 ;100km C0 ;120km	1 ;2X5 (10 pin) 2 ;2X10 (20 pin) 9 ;1X9 (9 pin)	I ;Indoor Use (0~70℃) O ;Outdoor Use (-40~85℃)	N ;No Shield M ;Metal coating

*Note 1 ;

- 220m with 62.5/125μm MMF @1.25Gbps
- 500m with 50/125μm MMF @1.25Gbps
- 200m with 62.5/125μm MMF @2.125Gbps

*Note 2 ; additional order information

- Connector type default is SC/PC and the default length of fiber is 1m
- In case of ordering pigtailed Bi-Di Transceiver, please specify specs. clearly if not default.

More Information

Teradian Inc.

Address 946, Dunsan-dong, Seo-gu, Daejeon, 302-120, Korea
Tel +82-42-476-4800, 4803(Oversea Sales Team)
Fax +82-42-476-4805
Homepage <http://www.teradian.com>
e-mail sales@teradian.com